

IN THE CLAIMS

Please amend claims 2, 3, 5 and 6 as follows:

1. (Original) A low temperature sintering ceramic composition containing Mg, Si, Bi and Li as constituent elements, wherein the composition comprises

MgO and SiO₂ in sum total in the range of from 64.0 to 99.2% by mass;

Bi₂O₃ in the range of from 0.4 to 33.0% by mass;

Li₂O in the range of from 0.4 to 3.0% by mass; and

MgO and SiO₂ are contained in the molar ratio of from 2: 1 to 2: 3.5, at least part thereof being contained as a complex oxide of Mg and Si.

2. (Currently Amended) The low temperature sintering ceramic composition according to claim 1, wherein the composition comprises

MgO and SiO₂ in sum total in the range of from 75.0 to 98.0% by mass;

Bi₂O₃ in the range of from 1.5 to 24.5% by mass; and

Li₂O in the range of from 0.5 to 3.0% by mass.

3. (Currently Amended) The low temperature sintering ceramic composition according to claim 1 [or 2], wherein the complex oxide is a forsterite system crystal phase ~~and/or enstatite system crystal phase~~; and

at least part of Bi₂O₃ and Li₂O is contained as a Bi₂O₃-SiO₂ system crystal phase and a Li₂O-SiO₂ system crystal phase.

4. (Currently Amended) The low temperature sintering ceramic composition according to claim 3, wherein the forsterite system crystal phase ~~and/or ensttite system crystal phase are~~ is contained by 60% or more of a total volume of the ceramic.

5. (Currently Amended) The low temperature sintering ceramic composition according to ~~any one of claims 1 to 4~~ claim 1, wherein a Qf value is 10,000 or more.

6. (Currently Amended) An electronic component comprising a wiring pattern on the low temperature sintering ceramic composition according to ~~any one of claims 1 to 5~~ claim 1.

7. (Currently Amended) The electronic component according to claim 6, wherein the wiring is formed by sintering a conductive paste containing at [lease] least one metal selected from Ag, Au and Cu.

8. (Original) A method of fabricating a low temperature sintering ceramic composition comprising:

molding a raw material powder containing one or both of a mixture of MgO and SiO₂ that contains MgO and SiO₂ at a molar ratio in the range of from 2: 1 to 2: 3.5 and a complex oxide thereof in the range of from 64.0 to 99.2% by mass, Bi₂O₃ in the range of from 0.4 to 33.0% by bass and Li₂O in the range of from 0.4 to 3.0% by mass into a predetermined shape followed by sintering at a temperature in the range of from 850 to 1000 °C.

9. (Original) The method according to claim 8, wherein the raw material powders are fine powders having a particle size of $2.0\ \mu\text{m}$ or less.

10. (New) The low temperature sintering ceramic composition according to claim 1, wherein the complex oxide is an enstatite system crystal phase; and

at least part of Bi_2O_3 and Li_2O is contained as a Bi_2O_3 - SiO_2 system crystal phase and a Li_2O - SiO_2 system crystal phase.

11. (New) The low temperature sintering ceramic composition according to claim 3, wherein the enstatite system crystal phase is contained by 60% or more of a total volume of the ceramic.